

Data Sheet May 2003 FN2896.5

## 600MHz, Very High Slew Rate Operational Amplifier

The Intersil HA-2539 represents the ultimate in high slew rate, wideband, monolithic operational amplifiers. It has been designed and constructed with the Intersil High Frequency Bipolar Dielectric Isolation process and features dynamic parameters never before available from a truly differential device.

With a  $600V/\mu s$  slew rate and a 600MHz gain bandwidth product, the HA-2539 is ideally suited for use in video and RF amplifier designs, in closed loop gains of 10 or greater. Full  $\pm 10V$  swing coupled with outstanding AC parameters and complemented by high open loop gain makes the devices useful in high speed data acquisition systems.

For further design assistance please refer to Application Note AN541 (Using the HA-2539 Very High Slew Rate Wideband Operational Amplifiers) and Application Note AN556 (Thermal Safe-Operating-Areas For High Current Operational Amplifiers.

For military grade product information, the HA-2539/883 data sheet is available upon request.

### Part Number Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.	
HA3-2539-5	0 to 75	14 Ld PDIP	E14.3	

#### **Features**

• Very High Slew Rate 600V/μs
Open Loop Gain
• Wide Gain-Bandwidth (AV $\geq$ 10) 600MHz
Power Bandwidth 9.5MHz
Low Offset Voltage
• Input Voltage Noise 6nV/\(\sqrt{Hz}\)
Output Voltage Swing

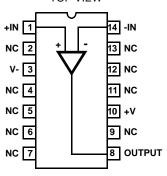
## Monolithic Bipolar Dielectric Construction

## **Applications**

- · Pulse and Video Amplifiers
- · Wideband Amplifiers
- · High Speed Sample-Hold Circuits
- RF Oscillators

### **Pinout**

#### HA-2539 (PDIP) TOP VIEW



NOTE: No-Connection (NC) leads may be tied to a ground plane for better isolation and heat dissipation.

### **Absolute Maximum Ratings**

Supply Voltage Between V+ and V- Terminals	35V
Differential Input Voltage	. 6V
Peak Output Current	0mA
Continuous Output Current	DMC

### **Operating Conditions**

Temperature Range	
HA-2539-5	0°C to 75°C

### **Thermal Information**

Thermal Resistance (Typical, Note 2)	$\theta_{JA}$ (oC/W)	θ <sub>JC</sub> (oC/W)
PDIP Package	95	N/A
Maximum Internal Quiescent Power Dissip	oation (Note	1)
Maximum Junction Temperature (Plastic F		
Maximum Storage Temperature Range .	65	5°C to 150°C
Maximum Lead Temperature (Soldering 1	0s)	300°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTES:

- Maximum power dissipation with load conditions must be designed to maintain the maximum junction temperature below 150°C for the plastic package. By using Application Note AN556 on Safe Operating Area equations, along with the thermal resistances, proper load conditions can be determined. Heat sinking is recommended above 75°C.
- 2. θJA is measured with the component mounted on a low effective thermal conductivity test board in free air. See Tech Brief TB379 for details.

### **Electrical Specifications** V<sub>SUPPLY</sub> = ±15V, R<sub>L</sub> = 1kW, C<sub>L</sub> < 10pF, Unless Otherwise Specified

PARAMETER	TEMP. (°C)	MIN	TYP	MAX	UNITS
INPUT CHARACTERISTICS	-		'	'	
Offset Voltage	25	-	8	15	mV
	Full	-	13	20	mV
Average Offset Voltage Drift	Full	-	20	-	μV/ <sup>o</sup> C
Bias Current	25	-	5	20	μА
	Full	-	-	25	μА
Offset Current	25	-	1	6	μА
	Full	-	-	8	μА
Input Resistance	25	-	10	-	kΩ
Input Capacitance	25	-	1	-	pF
Common Mode Range	Full	±10.0	-	-	V
Input Current Noise (f = 1kHz, R <sub>SOURCE</sub> = $0\Omega$ )	25	-	6	-	pA/√Hz
Input Voltage Noise (f = 1kHz, $R_{SOURCE} = 0\Omega$ )	25	-	6	-	nV/√ <del>Hz</del>
TRANSFER CHARACTERISTICS		1	1	1	
Large Signal Voltage Gain	25	10	15	-	kV/V
(Note 3)	Full	5	-		kV/V
Common Mode Rejection Ratio (Note 4)	Full	60	72	-	dB
Minimum Stable Gain	25	10	-	-	V/V
Gain Bandwidth (Notes 5, 6)	25	-	600	-	MHz

## $\textbf{Electrical Specifications} \hspace{0.5cm} V_{SUPPLY} = \pm 15 \text{V}, \hspace{0.1cm} R_L = 1 \text{kW}, \hspace{0.1cm} C_L < 10 \text{pF}, \hspace{0.1cm} \text{Unless Otherwise Specified} \hspace{0.1cm} \textbf{(Continued)}$

PARAMETER	TEMP. (°C)	MIN	TYP	MAX	UNITS			
OUTPUT CHARACTERISTICS	OUTPUT CHARACTERISTICS							
Output Voltage Swing (Notes 3, 10)	Full	±10.0	-	-	V			
Output Current (Note 3)	25	±10	±20	-	mA			
Output Resistance	25	-	30	-	Ω			
Full Power Bandwidth (Notes 3, 7)	25	8.7	9.5	-	MHz			
TRANSIENT RESPONSE (Note 8)	,	1	ı	1				
Rise Time	25	-	7	-	ns			
Overshoot	25	-	15	-	%			
Slew Rate	25	550	600	-	V/µs			
Settling Time: 10V Step to 0.1%	25	-	180	-	ns			
POWER REQUIREMENTS								
Supply Current	Full	-	20	25	mA			
Power Supply Rejection Ratio (Note 9)	Full	60	70	-	dB			

### NOTES:

- 3.  $R_L = 1k\Omega$ ,  $V_O = \pm 10V$ .
- 4.  $V_{CM} = \pm 10.0V$ .
- 5.  $V_O = 90 \text{mV}$ .
- 6.  $A_V = 10$ .
- 6.  $A_V$  = 10. 7. Full Power Bandwidth guaranteed based on slew rate measurement using: FPBW =  $\frac{\text{Slew Rate}}{2\pi V_{\text{PEAK}}}$
- 8. Refer to Test Circuits section of data sheet.
- 9.  $V_{SUPPLY} = +5V$ , -15V and +15V, -5V.
- 10. Guaranteed range for output voltage is  $\pm 10V$ . Functional operation outside of this range is not guaranteed.

### Test Circuits and Waveforms

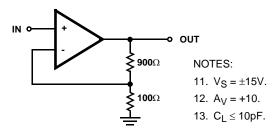
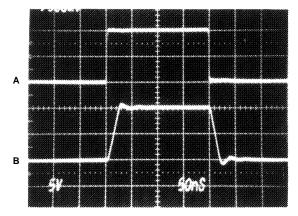


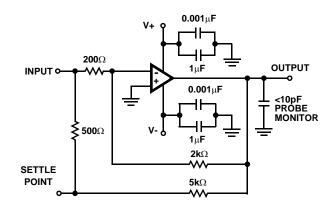
FIGURE 1. TEST CIRCUIT

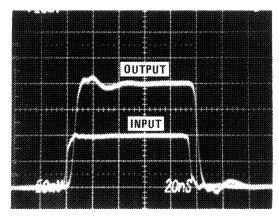


Vertical Scale: A = 0.5V/Div., B = 5.0V/Div.

Horizontal Scale: 50ns/Div.

FIGURE 2. LARGE SIGNAL RESPONSE





Vertical Scale: Input = 10mV/Div., Output = 50mV/Div. Horizontal Scale: 20ns/Div.

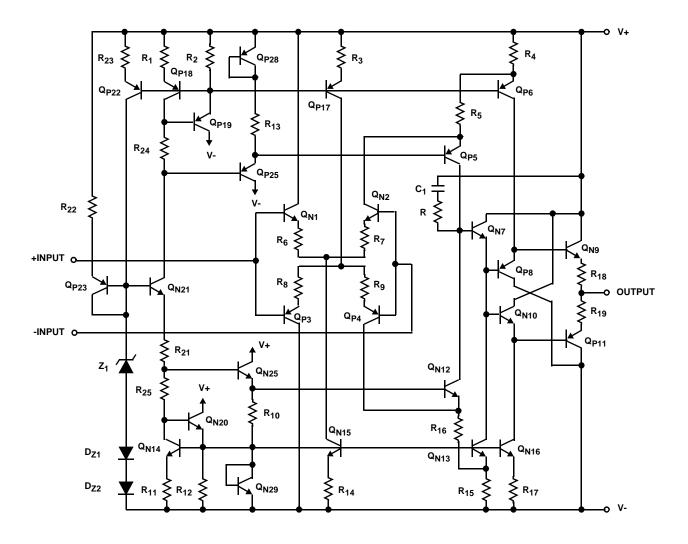
FIGURE 3. SMALL SIGNAL RESPONSE

### NOTES:

- 14.  $A_V = -10$ .
- 15. Load Capacitance should be less than 10pF.
- 16. It is recommended that resistors be carbon composition and that feedback and summing network ratios be matched to 0.1%.
- 17. SETTLE POINT (Summing Node) capacitance should be less than 10pF. For optimum settling time results, it is recommended that the test circuit be constructed directly onto the device pins. A Tektronix 568 Sampling Oscilloscope with S-3A sampling heads is recommended as a settle point monitor.

FIGURE 4. SETTLING TIME CIRCUIT

# Schematic Diagram



## **Typical Applications**

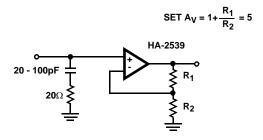


FIGURE 5. FREQUENCY COMPENSATION BY OVERDAMPING

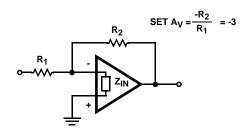


FIGURE 6. STABILIZATION USING  $Z_{\text{IN}}$ 

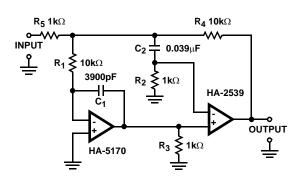


FIGURE 7. REDUCING DC ERRORS; COMPOSITE AMPLIFIER

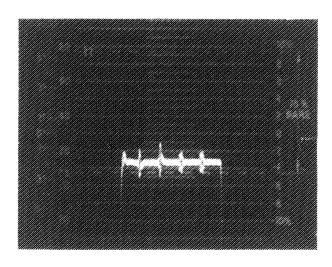


FIGURE 8. DIFFERENTIAL GAIN ERROR (3%) HA-2539 20dB VIDEO GAIN BLOCK

## **Typical Performance Curves**

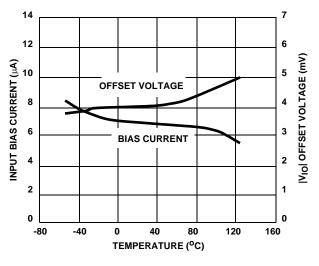


FIGURE 9. INPUT OFFSET VOLTAGE AND BIAS CURRENT vs TEMPERATURE

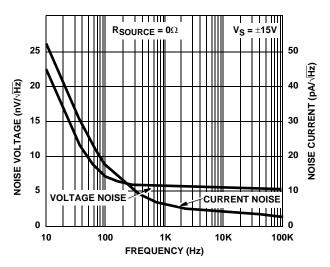
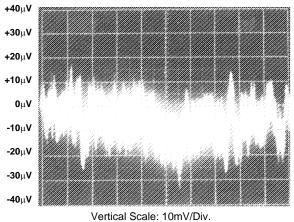


FIGURE 10. INPUT NOISE VOLTAGE AND NOISE CURRENT vs FREQUENCY

## Typical Performance Curves (Continued)



Horizontal Scale: 50ms/Div.

FIGURE 11. BROADBAND NOISE (0.1Hz TO 1MHz)

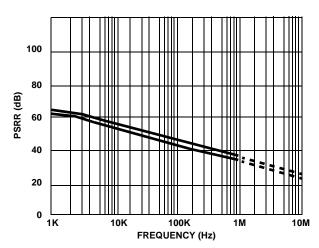


FIGURE 13. POWER SUPPLY REJECTION RATIO vs FREQUENCY

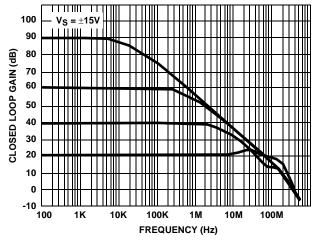


FIGURE 15. CLOSED LOOP FREQUENCY RESPONSE

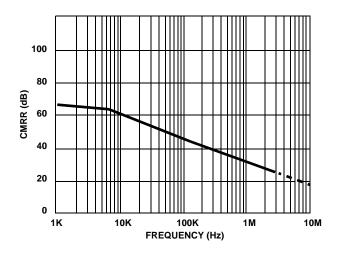


FIGURE 12. COMMON MODE REJECTION RATIO vs FREQUENCY

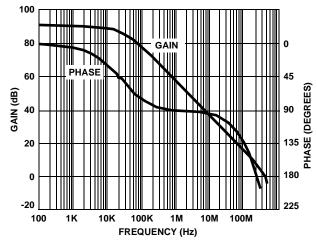


FIGURE 14. OPEN LOOP GAIN/PHASE vs FREQUENCY

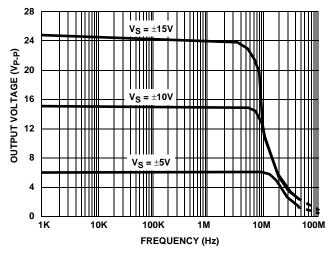


FIGURE 16. OUTPUT VOLTAGE SWING vs FREQUENCY

## Typical Performance Curves (Continued)

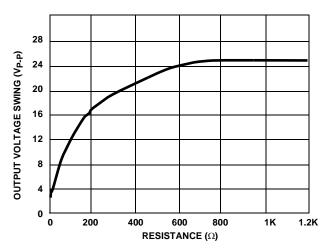


FIGURE 17. OUTPUT VOLTAGE SWING vs LOAD RESISTANCE

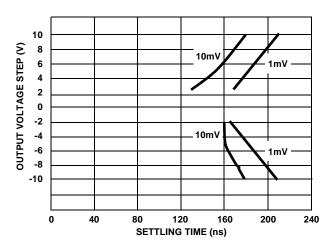


FIGURE 19. SETTLING TIME FOR VARIOUS OUTPUT STEP VOLTAGES

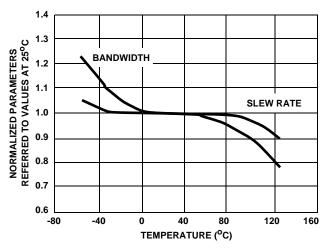


FIGURE 18. NORMALIZED AC PARAMETERS vs TEMPERATURE

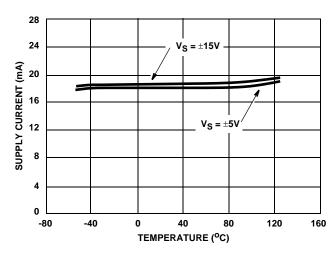


FIGURE 20. POWER SUPPLY CURRENT vs TEMPERATURE

## Die Characteristics

### **DIE DIMENSIONS:**

62 mils x 76 mils x 19 mils 1575μm x 1930μm x 483μm

### **METALLIZATION:**

Type: Al, 1% Cu Thickness: 16kÅ ±2kÅ

### **PASSIVATION:**

Type: Nitride (Si<sub>3</sub>N<sub>4</sub>) over Silox (SiO<sub>2</sub>, 5% Phos.)

Silox Thickness: 12kÅ ±2kÅ Nitride Thickness: 3.5kÅ ±1.5kÅ

## Metallization Mask Layout

### SUBSTRATE POTENTIAL (POWERED UP):

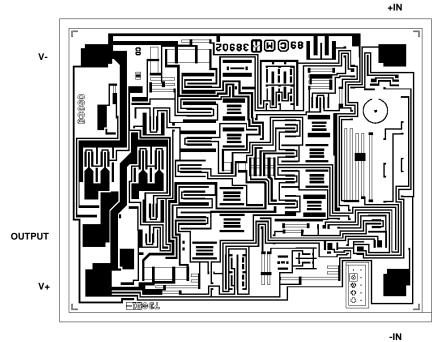
V-

### TRANSISTOR COUNT:

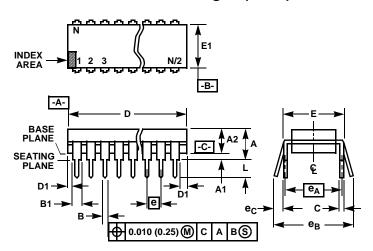
30

## PROCESS:

Bipolar Dielectric Isolation



## Dual-In-Line Plastic Packages (PDIP)



#### NOTES:

- 1. Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
- Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
- D, D1, and E1 dimensions do not include mold flash or protrusions.
   Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
- E and e<sub>A</sub> are measured with the leads constrained to be perpendicular to datum -C-.
- e<sub>B</sub> and e<sub>C</sub> are measured at the lead tips with the leads unconstrained. e<sub>C</sub> must be zero or greater.
- 8. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
- 9. N is the maximum number of terminal positions.
- Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

E14.3 (JEDEC MS-001-AA ISSUE D)
14 LEAD DUAL-IN-LINE PLASTIC PACKAGE

	INCHES MILLIME		ETERS		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
Α	-	0.210	-	5.33	4
A1	0.015	-	0.39	-	4
A2	0.115	0.195	2.93	4.95	-
В	0.014	0.022	0.356	0.558	-
B1	0.045	0.070	1.15	1.77	8
С	0.008	0.014	0.204	0.355	-
D	0.735	0.775	18.66	19.68	5
D1	0.005	-	0.13	-	5
Е	0.300	0.325	7.62	8.25	6
E1	0.240	0.280	6.10	7.11	5
е	0.100	BSC	2.54 BSC		-
e <sub>A</sub>	0.300	0.300 BSC		7.62 BSC	
e <sub>B</sub>	-	0.430	-	10.92	7
L	0.115	0.150	2.93	3.81	4
N	14		14		9

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